SGM8253-2 6MHz, High Voltage, High Precision, Low Noise, Rail-to-Rail I/O Operational Amplifier

GENERAL DESCRIPTION

The SGM8253-2 is a dual, low noise, high precision and high voltage operational amplifier. The device can operate from 4.5V to 36V single supply. It provides rail-to-rail input and output operation.

The SGM8253-2 offers a low offset voltage of $\pm 30\mu$ V (MAX) and a low bias current. The combination of characteristics makes it a good choice for temperature measurements, pressure and position sensors, strain gauge amplifiers and medical instrumentation, or any other 4.5V to 36V applications requiring precision, long-term stability and low drifting.

The SGM8253-2 is available in Green SOIC-8 and MSOP-8 packages. It is rated over the -40°C to +125°C temperature range.

FEATURES

- Low Offset Voltage: ±30µV (MAX)
- 0.1Hz to 10Hz Noise: 0.2µV_{P-P}
- Input Voltage Noise Density: 10.5nV/ $\sqrt{\text{Hz}}$ at 1kHz
- Open-Loop Voltage Gain: 160dB (TYP)
- CMRR:
 - 146dB (TYP)
 - 55dB (TYP) at 1MHz
- PSRR: 146dB (TYP)
- Gain-Bandwidth Product: 6MHz
- Slew Rate: 12V/µs
- Overload Recovery Time: 0.65µs
- Rail-to-Rail Input and Output
- Supply Voltage Range: 4.5V to 36V
- Low Quiescent Current: 2.4mA (TYP)
- -40°C to +125°C Operating Temperature Range
- Available in Green SOIC-8 and MSOP-8 Packages

APPLICATIONS

Pressure Sensors Temperature Measurements Precision Current Sensing Electronic Scales Strain Gauge Amplifiers Thermocouple Amplifiers Medical Instrumentation



PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SCM9252.2	SOIC-8	-40°C to +125°C	SGM8253-2XS8G/TR	SGM 82532XS8 XXXXX	Tape and Reel, 4000
SGM8253-2	MSOP-8	-40°C to +125°C	SGM8253-2XMS8G/TR	SGM15K XMS8 XXXXX	Tape and Reel, 4000

MARKING INFORMATION

NOTE: XXXXX = Date Code, Trace Code and Vendor Code.



Vendor Code
Trace Code

Date Code - Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, +Vs to -Vs	40V
Common Mode Voltage Range	
(-V _S) - 0.3	3V to (+V _S) + 0.3V
Differential Input Voltage Range	V _S to +V _S
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility ^{(1) (2)}	
HBM	±6000V
CDM	±1000V

NOTES:

1. For human body model (HBM), all pins comply with ANSI/ESDA/JEDEC JS-001 specifications.

2. For charged device model (CDM), all pins comply with ANSI/ESDA/JEDEC JS-002 specifications.

RECOMMENDED OPERATING CONDITIONS

Operating Voltage Range4.5V to 36V Operating Temperature Range-40°C to +125°C

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

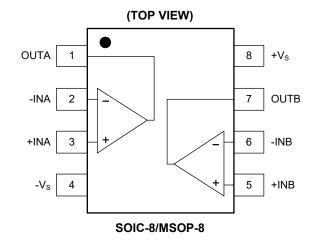
ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATIONS





ELECTRICAL CHARACTERISTICS

 $(V_S = \pm 2.5V \text{ to } \pm 18V, V_{CM} = 0V \text{ and } R_L = 10k\Omega \text{ connected to } 0V, \text{ Full} = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ typical values are at } T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.})$

PARAMETER	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS	
Input Characteristics	•						
Input Offset Voltage (V _{os})		+25°C		±2	±18		
input Oliset voltage (v _{os})		Full			±30	μV	
Input Offset Voltage Drift ($\Delta V_{OS}/\Delta T$)		Full		±37		nV/°C	
Input Bias Current (I _B)		+25°C		±200	±400	pА	
		Full			±6	nA	
Input Offset Current (Ios)		+25°C		±250	±1400	pА	
		Full			±3	nA	
Input Common Mode Voltage Range (V_{CM})		Full	(-V _s) - 0.1		(+V _S) + 0.1	V	
	$V_{\rm S}$ = 5V, $V_{\rm CM}$ = (-V _S) - 0.1V to (+V _S) + 0.1V	+25°C	108	126			
		Full	104				
	$V_{\rm S} = 5V, V_{\rm CM} = (-V_{\rm S}) - 0.1V$ to $(+V_{\rm S}) - 3V$	+25°C	110	140			
Common Mode Rejection Ratio ⁽¹⁾ (CMRR)		Full	106			dB	
	$V_{\rm S} = 36V, V_{\rm CM} = (-V_{\rm S}) - 0.1V$ to $(+V_{\rm S}) + 0.1V$	+25°C	122	146		ЧD	
	vs = 500, v _{CM} = (-vs) - 5.10 to (+vs) + 5.10		118				
	$V_{\rm S}$ = 36V, $V_{\rm CM}$ = (-V _S) - 0.1V to (+V _S) - 3V	+25°C	126	160		_	
		Full	120				
	$V_{\rm S} = \pm 2.25 V, V_{\rm OUT} = \pm 2 V$	+25°C	122	160			
Open-Loop Voltage Gain (A _{o∟})	vs = 12.23v, v ₀₀₁ = 12v		118			dB	
	V _s = ±18V, V _{OUT} = ±17.5V	+25°C	126	160		чъ	
	Vs - 1100, Vout - 117.50		120				
Output Characteristics							
	V _S = ±2.25V			10	18		
Output Voltage Swing from Rail (V _{OUT})	vs 12.20v	Full			25	mV	
	$V_s = \pm 18V$	+25°C		70	100		
	vs - ±10v	Full			135		
	V _s = ±2.25V	+25°C	±30	±40			
Output Short-Circuit Current (Isc)	V5 - 12.20V	Full	±22			mA	
	$V_s = \pm 18V$	+25°C	±35	±50			
	VS - 110V	Full	±20				
Power Supply							
Operating Voltage Range (V_S)		Full	4.5		36	V	
Quiescent Current (I _Q)	I _{OUT} = 0A	+25°C		2.4	3.1	mA	
	I _{OUT} – UA				3.3		
Power Supply Rejection Ratio ⁽¹⁾ (PSRR)			126	146		dB	
		Full	120			uр	

NOTE 1: PSRR and CMRR are affected by the matching between external gain-setting resistor ratios.



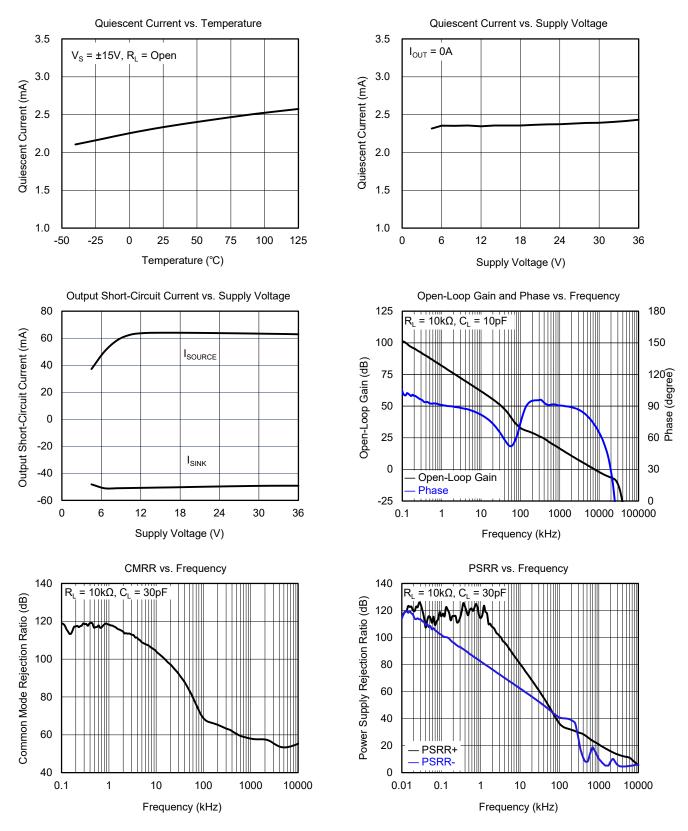
ELECTRICAL CHARACTERISTICS (continued) (V_S = $\pm 2.5V$ to $\pm 18V$, V_{CM} = 0V and R_L = $10k\Omega$ connected to 0V, Full = -40° C to $\pm 125^{\circ}$ C, typical values are at T_A = $\pm 25^{\circ}$ C, unless otherwise noted.)

PARAMETER	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS	
Dynamic Performance				•	•	•	
Cain Randwidth Braduat (CPR)	G = +100, C _L = 10pF	+25°C		12			
Gain-Bandwidth Product (GBP)	G = +1, C _L = 10pF	+25°C		6		MHz	
Slew Rate (SR)		+25°C		12		V/µs	
Common Mode Rejection Ratio (CMRR)	f = 1MHz	+25°C		55		dB	
Power Supply Rejection Ratio (PSRR)	f = 1MHz	+25°C		15		dB	
Settling Time to 0.1% (t _s)	V_{IN} = 1V step, G = +1	+25°C		8.5		μs	
Overload Recovery Time	$V_{IN} \times G > V_S$	+25°C		0.65		μs	
Total Harmonic Distortion + Noise (THD+N)	$V_{IN} = 2V_{P-P}, G = +1, f = 1kHz$	+25°C		0.0002		%	
Noise							
Input Voltage Noise	f = 0.1Hz to 10Hz	+25°C		0.2		μV _{P-P}	
	f = 0.1kHz	+25°C		10.5			
Input Voltage Noise Density (e _n)	f = 1kHz	+25°C		10.5		nV/√Hz	
	f = 10kHz	+25°C		10.5			



TYPICAL PERFORMANCE CHARACTERISTICS

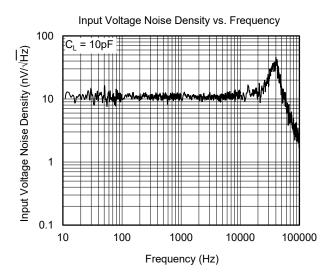
At T_A = +25°C, V_S = ±18V, unless otherwise noted.

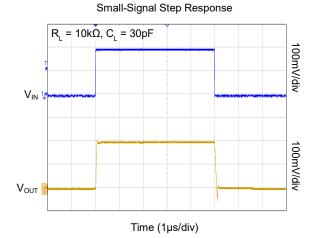


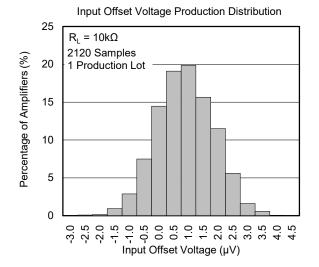
SG Micro Corp

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

At T_A = +25°C, V_S = ±18V, unless otherwise noted.

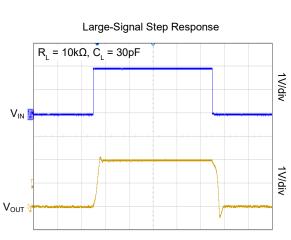




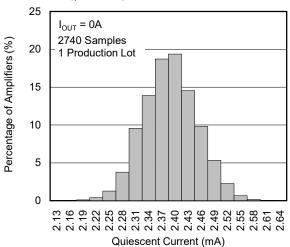


(Input voltage house (2001/div)

0.1Hz to 10Hz Input Voltage Noise



Time (1µs/div)



Quiescent Current Production Distribution

APPLICATION INFORMATION

Rail-to-Rail Input

When SGM8253-2 works at the power supply between 4.5V and 36V, the input common mode voltage range is from $(-V_S) - 0.1V$ to $(+V_S) + 0.1V$. In Figure 1, the ESD diodes between the inputs and the power supply rails will clamp the input voltage so that it does not exceed the rails.

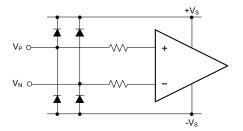


Figure 1. Input Equivalent Circuit

Rail-to-Rail Output

The SGM8253-2 supports rail-to-rail output operation. In single power supply application, for example, when +V_S = 36V, -V_S = GND, 10k Ω load resistor is tied from OUT pin to ground, the typical output swing range is from 0V to 35.93V.

Driving Capacitive Loads

The SGM8253-2 is unity-gain stable with heavy capacitive load. If greater capacitive load must be driven in application, the circuit in Figure 2 can be used. In this circuit, the IR drop voltage generated by $R_{\rm ISO}$ is compensated by feedback loop.

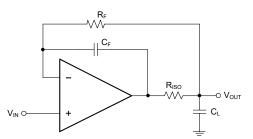


Figure 2. Circuit to Drive Heavy Capacitive Load

Power Supply Decoupling and Layout

A clean and low noise power supply is very important in amplifier circuit design. Besides of input signal noise, the power supply is one of important source of noise to the amplifier through $+V_S$ and $-V_S$ pins. Power supply bypassing is an effective method to clear up the noise at power supply, and the low impedance path to ground of decoupling capacitor will bypass the noise to GND. In application, 10μ F ceramic capacitor paralleled with 0.1μ F or 0.01μ F ceramic capacitor is used in Figure 3. The ceramic capacitors should be placed as close as possible to $+V_S$ and $-V_S$ power supply pins.

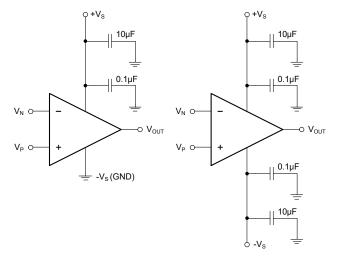


Figure 3. Amplifier Power Supply Bypassing

Grounding

In low speed application, one node grounding technique is the simplest and most effective method to eliminate the noise generated by grounding. In high speed application, the general method to eliminate noise is to use a complete ground plane technique, and the whole ground plane will help distribute heat and reduce EMI noise pickup.

Reduce Input-to-Output Coupling

To reduce the input-to-output coupling, the input traces must be placed as far away from the power supply or output traces as possible. The sensitive trace must not be placed in parallel with the noisy trace in the same layer. They must be placed perpendicularly in different layers to reduce the crosstalk. These PCB layout techniques will help to reduce unwanted positive feedback and noise.



APPLICATION INFORMATION (continued)

Typical Application Circuits Difference Amplifier

The circuit in Figure 4 is a design example of classical difference amplifier. If $R_4/R_3 = R_2/R_1$, then $V_{OUT} = (V_P - V_N) \times R_2/R_1 + V_{REF}$.

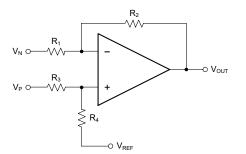


Figure 4. Difference Amplifier

High Input Impedance Difference Amplifier

The circuit in Figure 5 is a design example of high input impedance difference amplifier. The added amplifiers at the input are used to increase the input impedance and eliminate drawback of low input impedance in Figure 4.

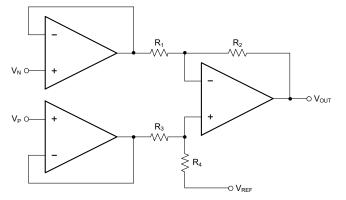


Figure 5. High Input Impedance Difference Amplifier

Active Low-Pass Filter

The circuit in Figure 6 is a design example of active low-pass filter, the DC gain is equal to $-R_2/R_1$ and the -3dB corner frequency is equal to $1/(2\pi R_2 C)$. In this design, the filter bandwidth must be less than the bandwidth of the amplifier, and the resistor values must be selected as low as possible to reduce ringing or oscillation generated by the parasitic parameters in PCB layout.

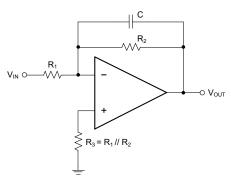


Figure 6. Active Low-Pass Filter



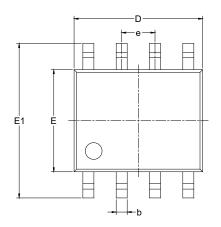
REVISION HISTORY

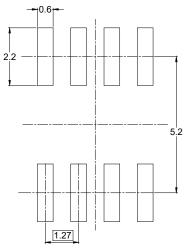
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (NOVEMBER 2024) to REV.A	Page
Changed from product preview to production data	All

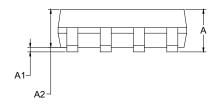


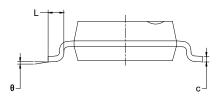
PACKAGE OUTLINE DIMENSIONS SOIC-8





RECOMMENDED LAND PATTERN (Unit: mm)





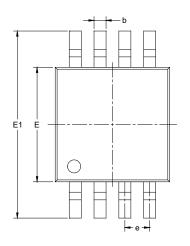
Symbol	-	nsions meters	Dimensions In Inches		
	MIN	MAX	MIN	MAX	
A	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
с	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.27 BSC		0.050	BSC	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	

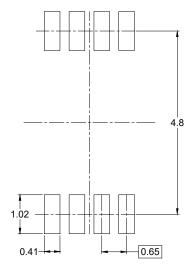
NOTES: 1. Body dimensions do not include mode flash or protrusion.

2. This drawing is subject to change without notice.

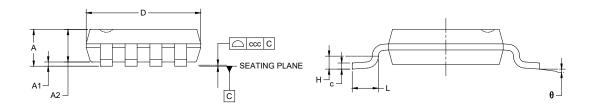


PACKAGE OUTLINE DIMENSIONS MSOP-8





RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Di	mensions In Millimete	ers				
Symbol	MIN	NOM	МАХ				
A	-	-	1.100				
A1	0.000	-	0.150				
A2	0.750	-	0.950				
b	0.220	-	0.380				
С	0.080	0.080 -					
D	2.800	-	3.200				
E	2.800	-	3.200				
E1	4.650	-	5.150				
е		0.650 BSC					
L	0.400	-	0.800				
Н	0.250 TYP						
θ	0°	-	8°				
ccc	0.100						

NOTES:

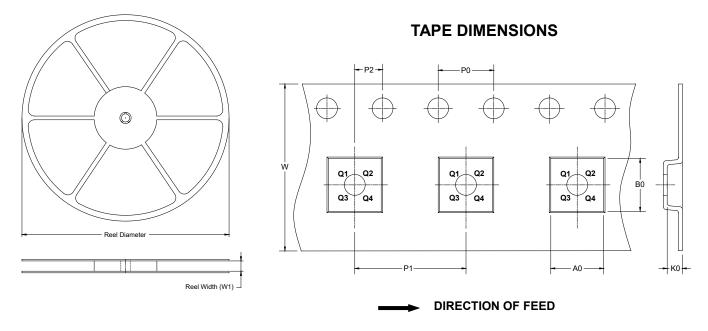
This drawing is subject to change without notice.
The dimensions do not include mold flashes, protrusions or gate burrs.

3. Reference JEDEC MO-187.



TAPE AND REEL INFORMATION

REEL DIMENSIONS

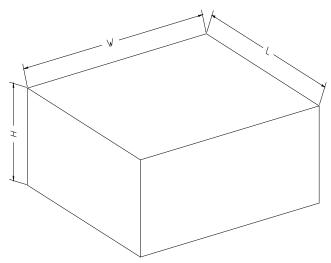


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOIC-8	13″	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1
MSOP-8	13″	12.4	5.20	3.30	1.50	4.0	8.0	2.0	12.0	Q1

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton	
13″	386	280	370	5	DD0002

